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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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Chip Multilayer Ceramic Capacitors for Automotive GCM1555C1H1R0BA16 (0402, C0G:EIA, 1pF, DC50V)

_: packaging code

Reference Sheet

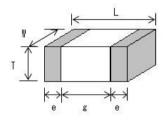
1.Scope

This product specification is applied to Chip Multilayer Ceramic Capacitors used for Automotive Electronic equipment.

2.MURATA Part NO. System

(Ex.) GCM	15	5	5C	1H	1R0	В	A16	D
	(1)L/W Dimensions	(2)T Dimensions	(3)Temperature	(4)Rated	(5)Nominal	(6)Capacitance	(7)Murata's Control	(8)Packaging Code

3. Type & Dimensions



(Unit:mm)

1

(1)-1 L	(1)-2 W	(2) T	е	g
1.0±0.05	0.5±0.05	0.5±0.05	0.15 to 0.35	0.3 min.

4.Rated value

	Tillated Value						
	(3) Temperature Characteristics (Public STD Code):C0G(EIA) Temp. coeff or Cap. Change (Ref.Temp.) 25 to 125 °C (25 °C)		(4) Rated	(5) Nominal	(6) Capacitance	Specifications and Test Methods (Operating Temp. Range)	
			Voltage	Capacitance	Tolerance		
			DC 50 V	1 pF	±0.1 pF	-55 to 125 °C	

5.Package

U U.U		
mark	(8) Packaging	Packaging Unit
D	φ180mm Reel PAPER W8P2	10000 pcs./Reel
W	φ180mm Reel PAPER W8P1	20000 pcs./Reel
J	φ330mm Reel PAPER W8P2	50000 pcs./Reel

Product specifications in this catalog are as of Jun.4,2018,and are subject to change or obsolescence without notice. Please consult the approval sheet before ordering.

Please read rating and !Cautions first.

No				· · · · ·				
	AEC-020	00 Test Item	Sp Temperature	pecification.	\dashv		AEC-Q200 Test M	lethod
Ĺ	420		Compensating Type	High Dielectric Type				
1	Pre-and Po Electrical T			-	•			
2	High Temp	erature	The measured and observed charac	teristics should satisfy the	Solder	the capacitor c	n the test substrate(glass epoxy board).
	Exposure (Storage)	specifications in the following table.		Set the	capacitor for 1	000+/-12h at 150+/-	3°C.
		Appearance	No marking defects		Set for	24+/-2h at roo	m temperature, then	measure.
		Capacitance	Within +/-2.5% or +/-0.25pF	Within +/-10.0%				
		Change	(Whichever is larger)		 Initia 	al measuremen	t for high dielectric c	onstant type
		Q or D.F.	30pFmin. : Q≧1000	R7/L8 W.V.: 25Vmin. : 0.03 max.	Perform	n a heat treatm	ent at 150+0/-10 °Cf	or 1h and then sit
			30pFmax.: Q ≧400+20C	W.V.: 16V/10V : 0.05 max.	for 24+	/-2h at room te	mperature.Perform t	he initial measurement.
			C: Nominal Capacitance(pF)	R9: 0.075max.				
		I.R.	5C/5G/R7/L8 : More than 10,000M Ω	Ω or $500 \Omega \cdot F(Whichever is smaller)$				
		25°C	R9 : More than $3000M\Omega$ or 150Ω •F	(Whichever is smaller)				
3	Temperatu	re Cycling	The measured and observed characteristics should satisfy the			the capacitor o	n the test substrate(glass epoxy board).
			specifications in the following table.			n cycle test acc	ording to the four he	eat treatments listed
		Appearance	No marking defects			ollowing table.		
				1	Set for	24+/-2h at roo	m temperature, then	measure.
		Capacitance	Within +/-2.5% or +/-0.25pF	Within +/-10.0%	Step	Time (min)	Cyc	cles
		Change	(Whichever is larger)			Time (min)	1000 (for ΔC/R7)	300 (for 5G/L8/R9)
					1 2	15+/-3	-55°C+0/-3	-55°C+0/-3
		Q or D.F.	30pFmin. : Q≧1000	R7/L8 W.V.: 25Vmin. : 0.03 max.	3	15+/-3	Room 125°C+3/-0	Room 150°C+3/-0
			30pFmax.: Q ≧400+20C	W.V.: 16V/10V : 0.05 max.	4	1	Room	Room
	I.R. 25°C		C: Nominal Capacitance(pF)	R9 : 0.075 max.				
							t for high dielectric o	*1
			More than 10 000MO or 5000 . E				ent at 150+0/-10 °Cf	
İ			More than 10,000MΩ or 500Ω \cdot F			r-∠n at room te	inperature.Perform t	he initial measurement.
			(Whichever is smaller)					
4	Destructive	<u> </u>	No defects or abnormalities			N-469.		
ı .	Physical A		The defects of abriefinances		1 61 LIA-403.			
5	Moisture R		The measured and observed charac	teristics should satisfy the	Solder the capacitor on the test substrate(glass epoxy board).			
			specifications in the following table.	······································	Apply the 24h heat (25°C to 65°C) and humidity (80%RH to 98%RH) treatment shown below, 10 consecutive times. Set for 24+/-2h at room temperature, then measure.			
		Appearance	No marking defects					
		1 10 10 10 10 10 10 10 10 10 10 10 10 10						
		Capacitance	Within +/-3.0% or +/-0.30pF	Within +/-12.5%				
		Change	(Whichever is larger)		Temperature Humidity Humidity $80 \sim 98\%$ Humidity $80 \sim 98\%$ Humidity $80 \sim 98\%$ Humidity			
			,		(°C) 70		-98% ↓ 90~	98% 90~98%
		Q or D.F.	30pFmin. : Q≧350	R7/L8: W.V.: 35Vmin.: 0.03 max.	65 60			
			10pF and over, 30pF and below:				17	
			ropi and over, copi and below.	W.V.: 25Vmax. : 0.05 max.	55			
			Q≧275+5C/2	W.V.: 25Vmax. : 0.05 max. R9 : 0.075max.	55 50 45			
ı					55 50			
			Q≧275+5C/2		55 50 45 40 35 30			
			Q≧275+5C/2 10pFmax.: Q ≧200+10C		55 50 45 40 35 30 25 20		+10	
		I.R.	Q≧275+5C/2 10pFmax.: Q ≧200+10C	R9 : 0.075max.	55 50 45 40 35 30 25 20 15	-73-	+10 - 2 °C	
		I.R. 25°C	Q≧275+5C/2 10pFmax.: Q ≧200+10C C: Nominal Capacitance(pF)	R9 : 0.075max. 2 or 500 Ω •F(Whichever is smaller)	55 50 45 40 35 30 25 20 15 10 5	Init al measur	+10 - 2 °C	
			Q≧275+5C/2 10pFmax.: Q ≧200+10C C: Nominal Capacitance(pF) 5C/5G/R7/L8 : More than 10,000MΩ	R9 : 0.075max. 2 or 500 Ω •F(Whichever is smaller)	55 50 45 40 35 30 25 20 15 10 5	Init al measur	+10 - 2 °C	
			Q≧275+5C/2 10pFmax.: Q ≧200+10C C: Nominal Capacitance(pF) 5C/5G/R7/L8 : More than 10,000MΩ	R9 : 0.075max. 2 or 500 Ω •F(Whichever is smaller)	55 50 45 40 35 30 25 20 15 10 5	Irrit al measur		4hours 14 15 16 17 18 19 20 21 22 23 24
			Q≧275+5C/2 10pFmax.: Q ≧200+10C C: Nominal Capacitance(pF) 5C/5G/R7/L8 : More than 10,000MΩ	R9 : 0.075max. 2 or 500 Ω •F(Whichever is smaller)	55 50 45 40 35 30 25 20 15 10 5 0 -5 -10		—— → Ho	urs
			Q≧275+5C/2 10pFmax.: Q ≧200+10C C: Nominal Capacitance(pF) 5C/5G/R7/L8 : More than 10,000MΩ	R9 : 0.075max. 2 or 500 Ω •F(Whichever is smaller)	55 55 55 50 45 40 35 52 50 50 5 5 5 6 7 10 6 7 10 11 11 12 11 11 11 11 11 11 11 11 11 11	al measuremen	→ Ho t for high dielectric c	urs onstant type
			Q≧275+5C/2 10pFmax.: Q ≧200+10C C: Nominal Capacitance(pF) 5C/5G/R7/L8 : More than 10,000MΩ	R9 : 0.075max. 2 or 500 Ω •F(Whichever is smaller)	55 50 45 40 35 30 25 5 10 5 0 -5 -10	al measuremen n a heat treatm	t for high dielectric cent at 150+0/-10 °Cf	urs onstant type
			Q≧275+5C/2 10pFmax.: Q ≧200+10C C: Nominal Capacitance(pF) 5C/5G/R7/L8 : More than 10,000MΩ	R9 : 0.075max. 2 or 500 Ω •F(Whichever is smaller)	55 50 45 40 35 30 25 5 10 5 0 -5 -10	al measuremen n a heat treatm	t for high dielectric cent at 150+0/-10 °Cf	onstant type or 1h and then sit
6	Biased Hur	25°C	Q≧275+5C/2 10pFmax.: Q ≧200+10C C: Nominal Capacitance(pF) 5C/5G/R7/L8 : More than 10,000MΩ	R9: 0.075max. 2 or 500 Ω • F(Whichever is smaller) (Whichever is smaller)	55 50 45 40 35 30 25 5 10 5 0 -5 -10	al measuremen n a heat treatm /-2h at room te	t for high dielectric cent at 150+0/-10 °Cf	urs onstant type or 1h and then sit he initial measurement.
6	Biased Hur	25°C	Q≧275+5C/2 10pFmax.: Q ≧200+10C C: Nominal Capacitance(pF) 5C/5G/R7/L8 : More than 10,000MΩ R9 : More than 3000MΩ or 150Ω • F	R9: 0.075max. 2 or 500 Ω • F(Whichever is smaller) (Whichever is smaller)	55 50 45 40 35 30 25 5 10 5 0 -5 -10 • Initia Perform for 24+	al measuremen n a heat treatm /-2h at room te the capacitor c	t for high dielectric cent at 150+0/-10 °Cf mperature.Perform to the test substrate(urs onstant type or 1h and then sit he initial measurement.
6	Biased Hur	25°C	Q≧275+5C/2 10pFmax.: Q ≧200+10C C: Nominal Capacitance(pF) 5C/5G/R7/L8 : More than 10,000MΩ R9 : More than 3000MΩ or 150Ω • F	R9: 0.075max. 2 or 500 Ω • F(Whichever is smaller) (Whichever is smaller)	55 50 45 40 35 30 25 5 20 15 10 5 0 -5 -10 • Initia Perform for 24+,	al measuremenn a heat treatm /-2h at room te the capacitor on	t for high dielectric cent at 150+0/-10 °Cf mperature.Perform to the test substrate(onstant type or 1h and then sit he initial measurement. glass epoxy board). c (add 6.8kΩ resister)
6	Biased Hur	25°C	Q≧275+5C/2 10pFmax.: Q ≧200+10C C: Nominal Capacitance(pF) 5C/5G/R7/L8 : More than 10,000MΩ R9 : More than 3000MΩ or 150Ω • F	R9: 0.075max. 2 or 500 Ω • F(Whichever is smaller) (Whichever is smaller)	55 50 45 40 35 20 15 10 5 0 0 -5 -10 • Initia Perform for 24+,	al measuremenn a heat treatm /-2h at room te the capacitor one rated voltag -3°C and 80%F	t for high dielectric cent at 150+0/-10 °Cf mperature.Perform to the test substrate(e and 1.3+0.2/-0Vdc	onstant type or 1h and then sit he initial measurement. glass epoxy board). (add 6.8kΩ resister) ty for 1000+/-12h.
6	Biased Hur	25°C	Q≧275+5C/2 10pFmax.: Q ≧200+10C C: Nominal Capacitance(pF) 5C/5G/R7/L8 : More than 10,000MΩ R9 : More than 3000MΩ or 150Ω • F	R9: 0.075max. 2 or 500 Ω • F(Whichever is smaller) (Whichever is smaller)	55 50 45 40 35 20 15 10 5 0 0 -5 -10 • Initia Perform for 24+, Solder (Apply the Cartes)	al measuremen n a heat treatm /-2h at room te the capacitor of he rated voltag -3°C and 80%F arge/discharge	t for high dielectric cent at 150+0/-10 °Cf mperature.Perform to the test substrate(e and 1.3+0.2/-0Vdc RH to 85%RH humidicurrent is less than	onstant type or 1h and then sit he initial measurement. glass epoxy board). (add 6.8kΩ resister) ty for 1000+/-12h.
6	Biased Hur	25°C midity Appearance	Q≧275+5C/2 10pFmax.: Q ≧200+10C C: Nominal Capacitance(pF) 5C/5G/R7/L8 : More than 10,000MΩ R9 : More than 3000MΩ or 150Ω • F The measured and observed charac specifications in the following table. No marking defects	R9: 0.075max. 2 or 500 Ω • F(Whichever is smaller) (Whichever is smaller)	55 50 45 40 35 20 15 10 5 0 0 -5 -10 • Initia Perform for 24+, Solder (Apply the Cartes)	al measuremen n a heat treatm d-2h at room te the capacitor of the rated voltag 3°C and 80%F arge/discharge	t for high dielectric cent at 150+0/-10 °Cf mperature.Perform to the test substrate(e and 1.3+0.2/-0Vdc RH to 85%RH humidicurrent is less than	onstant type or 1h and then sit he initial measurement. glass epoxy board). c (add 6.8kΩ resister) ty for 1000+/-12h. 50mA.
6	Biased Hur	25°C midity Appearance Capacitance	Q≧275+5C/2 10pFmax.: Q ≧200+10C C: Nominal Capacitance(pF) 5C/5G/R7/L8 : More than 10,000MΩ R9 : More than 3000MΩ or 150Ω • F The measured and observed charac specifications in the following table. No marking defects Within +/-3.0% or +/-0.30pF	R9: 0.075max. 2 or 500 Ω • F(Whichever is smaller) (Whichever is smaller)	55 50 40 45 40 35 50 50 50 50 50 50 50 50 50 50 50 50 50	al measuremen n a heat treatm d'-2h at room te the capacitor of the rated voltag 3°C and 80%F arge/discharge e and set for 2	t for high dielectric cent at 150+0/-10 °Cf mperature.Perform to the test substrate(e and 1.3+0.2/-0Vdc RH to 85%RH humidicurrent is less than	onstant type or 1h and then sit he initial measurement. glass epoxy board). c (add 6.8kΩ resister) ty for 1000+/-12h. 50mA. erature, then measure.
6	Biased Hur	25°C midity Appearance Capacitance Change	Q≧275+5C/2 10pFmax.: Q ≥200+10C C: Nominal Capacitance(pF) 5C/5G/R7/L8 : More than 10,000MΩ R9 : More than 3000MΩ or 150Ω • F The measured and observed charac specifications in the following table. No marking defects Within +/-3.0% or +/-0.30pF (Whichever is larger)	R9:0.075max. or 500 \Omega \cdot F(Whichever is smaller) (Whichever is smaller) eteristics should satisfy the	55 50 45 40 35 30 25 50 0 -5 -10 Initia Perform for 24+, Solder (Apply the Care Apply the Care	al measuremen n a heat treatm d'-2h at room te the capacitor of the rated voltag 3°C and 80%F arge/discharge e and set for 2	t for high dielectric cent at 150+0/-10 °Cf mperature.Perform time the test substrate(e and 1.3+0.2/-0Vdc RH to 85%RH humidicurrent is less than 4+/-2h at room temporare to the test substrate to the test substrate that the	onstant type or 1h and then sit he initial measurement. glass epoxy board). c (add 6.8kΩ resister) ty for 1000+/-12h. 50mA. erature, then measure.
6	Biased Hur	25°C midity Appearance Capacitance Change	Q≧275+5C/2 10pFmax.: Q ≥200+10C C: Nominal Capacitance(pF) 5C/5G/R7/L8 : More than 10,000MΩ R9 : More than 3000MΩ or 150Ω • F The measured and observed charac specifications in the following table. No marking defects Within +/-3.0% or +/-0.30pF (Whichever is larger) 30pF and over: Q≧200	R9:0.075max. 2 or 500 \(\Omega \cdot \text{F(Whichever is smaller)} \) (Whichever is smaller) steristics should satisfy the Within +/-12.5% R7/L8 W.V.: 35Vmin.: 0.035 max.*	55 50 45 40 35 30 25 50 0 -5 -10 Initia Perform for 24+, Apply tt at 85+/- Remove Initia Perform	al measuremen n a heat treatm d'-2h at room te the capacitor of the rated voltag 3°C and 80%F arge/discharge e and set for 2 al measuremen n a heat treatm	t for high dielectric cent at 150+0/-10 °Cf mperature.Perform time the test substrate(e and 1.3+0.2/-0Vdc RH to 85%RH humidicurrent is less than 4+/-2h at room temporature tent at 150+0/-10 °Cf	onstant type or 1h and then sit he initial measurement. glass epoxy board). c (add 6.8kΩ resister) ty for 1000+/-12h. 50mA. erature, then measure.
6	Biased Hur	25°C midity Appearance Capacitance Change	Q≥275+5C/2 10pFmax.: Q≥200+10C C: Nominal Capacitance(pF) 5C/5G/R7/L8 : More than 10,000MΩ R9 : More than 3000MΩ or 150Ω • F The measured and observed charac specifications in the following table. No marking defects Within +/-3.0% or +/-0.30pF (Whichever is larger) 30pF and over: Q≥200 30pF and below: Q≥100+10C/3	R9:0.075max. 2 or 500 \(\Omega \cdot \text{F(Whichever is smaller)} \) (Whichever is smaller) steristics should satisfy the Within +/-12.5% R7/L8 W.V.: 35Vmin.: 0.035 max.* * GCM188L81H221 to 103: 0.05 max.	55 50 45 40 35 30 25 50 0 -5 -10 Initia Perform for 24+, Apply tt at 85+/- Remove Initia Perform	al measuremen n a heat treatm d'-2h at room te the capacitor of the rated voltag 3°C and 80%F arge/discharge e and set for 2 al measuremen n a heat treatm	t for high dielectric cent at 150+0/-10 °Cf mperature.Perform time the test substrate(e and 1.3+0.2/-0Vdc RH to 85%RH humidicurrent is less than 4+/-2h at room temporature tent at 150+0/-10 °Cf	onstant type or 1h and then sit he initial measurement. glass epoxy board). c (add 6.8kΩ resister) ty for 1000+/-12h. 50mA. erature, then measure. onstant type or 1h and then sit
6	Biased Hur	25°C midity Appearance Capacitance Change	Q≥275+5C/2 10pFmax.: Q≥200+10C C: Nominal Capacitance(pF) 5C/5G/R7/L8 : More than 10,000MΩ R9 : More than 3000MΩ or 150Ω • F The measured and observed charac specifications in the following table. No marking defects Within +/-3.0% or +/-0.30pF (Whichever is larger) 30pF and over: Q≥200 30pF and below: Q≥100+10C/3	R9:0.075max. or 500 \text{\$\Omega\$} \cdot \text{\$(Whichever is smaller)} \ (Whichever is smaller) eteristics should satisfy the Within +/-12.5% R7/L8 W.V.: 35Vmin.: 0.035 max.* * GCM188L81H221 to 103: 0.05 max. W.V.: 25Vmax.: 0.05 max.	55 50 45 40 35 30 25 50 0 -5 -10 Initia Perform for 24+, Apply tt at 85+/- Remove Initia Perform	al measuremen n a heat treatm d'-2h at room te the capacitor of the rated voltag 3°C and 80%F arge/discharge e and set for 2 al measuremen n a heat treatm	t for high dielectric cent at 150+0/-10 °Cf mperature.Perform time the test substrate(e and 1.3+0.2/-0Vdc RH to 85%RH humidicurrent is less than 4+/-2h at room temporature tent at 150+0/-10 °Cf	onstant type or 1h and then sit he initial measurement. glass epoxy board). c (add 6.8kΩ resister) ty for 1000+/-12h. 50mA. erature, then measure. onstant type or 1h and then sit

■AEC-Q200 Murata Standard Specification and Test Methods

			Spi	ecification.			
No	AEC-Q20	0 Test Item	Temperature	High Dielectric Type	AEC-Q200 Test Method		
7	Operational L	ifo	Compensating Type The measured and observed chara	, ,,	Solder the capacitor on the test substrate(glass epoxy board).		
1	Operational L	ile	specifications in the following table	•	Apply 200% of the rated voltage for 1000+/-12h at 125+/-3°C		
		Appearance	No marking defects		(for ΔC/R7), 150+/-3°C(for 5G/L8/R9).		
					The charge/discharge current is less than 50mA.		
		Capacitance	Within +/-3.0% or +/-0.30pF	Within +/-12.5%	Set for 24+/-2h at room temperature, then measure.		
		Change	(Whichever is larger)		,		
		Q or D.F.	30pFmin. : Q≧350	R7/L8 : W.V.: 35Vmin.: 0.035 max.*	Initial measurement for high dielectric constant type.		
			10pF and over, 30pF and below:		Apply the test voltage at the max. operating temp. +/-3°C for 1h		
			Q≧275+5C/2	GCM188L81H221 to 103: 0.04 max.	and then let sit for 24+/-2h at room temperature, then measure.		
			10pFmax.: Q ≧200+10C	W.V.: 25Vmax. : 0.05 max.			
			C: Nominal Capacitance(pF)	R9: 0.075max.			
		I.R.	More than 1,000MΩ or 50Ω•F				
		25°C	(Whichever is smaller)				
8	External Visual No defects or abnormalities		Visual inspection				
o	External visua				visual ilispection		
9	Physical Dime	ension	Within the specified dimensions		Using Measuring instrument of dimension.		
10	Resistance to	Appearance	No marking defects		Per MIL-STD-202 Method 215		
	Solvents				Solvent 1 : 1 part (by volume) of isopropyl alcohol		
		Capacitance	Within the specified initial value.		3 parts (by volume) of mineral spirits		
					Solvent 2 : Terpene defluxer		
		Q or D.F.	Within the specified initial value.		Solvent 3: 42 parts (by volume) of water		
					1 part (by volume) of propylene glycol monomethyl ether		
					1 part (by volume) of monoethanolamine		
		I.R.	More than $10,000M\Omega$ or $500\Omega \cdot F$				
		25°C	(Whichever is smaller)				
11	Mechanical	Appearance	No marking defects		Solder the capacitor on the test substrate(glass epoxy board).		
	Shock				Three shocks in each direction should be applied along 3 mutually		
		Capacitance	Within the specified initial value.		perpendicular axes of the test specimen (18 shocks). The specified test pulse should be Half-sine and should have a duration :0.5ms, peak value:1500g and velocity change: 4.7m/s.		
		Q or D.F.	Within the appoified initial value				
		Q OI D.I .	Within the specified initial value.				
		I.R.	More than $10,000\text{M}\Omega$ or $500\Omega \cdot \text{F}$				
		25°C	(Whichever is smaller)				
12	Vibration	Appearance	No defects or abnormalities		Solder the capacitor on the test substrate(glass epoxy board).		
					The capacitor should be subjected to a simple harmonic motion having		
		Capacitance	Within the specified initial value.		a total amplitude of 1.5mm, the frequency being varied uniformly		
					between the approximate limits of 10 and 2000Hz.		
		Q or D.F.	Within the specified initial value.		The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes.		
		I.R.	More than 10,000MΩ or $500Ω \cdot F$		This motion should be applied for 12 items in each 3 mutually		
		25°C	(Whichever is smaller)		perpendicular directions (total of 36 times).		
			(Trinonever te emailer)		,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,		
13	Resistance to	<u> </u>	The measured and observed chara	cteristics should satisfy the	Immerse the capacitor in Sn-3.0Ag-0.5Cu solder solution or an eutectic		
	Soldering Hea	at	specifications in the following table	<u> </u>	solder solution at 260+/-5°C for 10+/-1s.		
		Appearance	No marking defects		Set at room temperature for 24+/-2h, then measure.		
		Capacitance	Within the specified initial value.		Initial measurement for high dielectric constant type		
		Q or D.F.	Within the specified initial value.		Perform a heat treatment at 150+0/-10 °C for 1h and then set for 24+/-2h at room temperature.		
		Q 0. D.1 .	The specified initial value.		Perform the initial measurement.		
		I.R.	More than $10,000\text{M}\Omega$ or $500\Omega \cdot \text{F}$				
		25°C (Whichever is smaller)					
		25°C	(Whichever is smaller)				

■AEC-Q200 Murata Standard Specification and Test Methods

	AFC OOOD Took Hom		Sp	pecification.				
No	AEC-Q2	00 Test Item	Temperature Compensating Type	High Dielectric Type	AEC-Q200 Test Method			
14	Thermal Sh	lock	The measured and observed characterspecifications in the following table.	eristics should satisfy the	Solder the capacitor on the test substrate(glass epoxy board). Perform the 300 cycles according to the two heat treatments listed			
		Appearance	No marking defects	T	in the following table(Maximum transfer time is 20s). Set for 24+/-2h at room temperature, then measure.			
		Capacitance Change	Within +/-2.5% or +/-0.25pF (Whichever is larger)	Within +/-10.0%	Step 1 2 Temp. -55+0/-3 125+3/-0 (forΔC/R7)			
		Q or D.F.	30pFmin. : Q≥1000 30pFmax.: Q≥400+20C C: Nominal Capacitance(pF)	R7/L8: W.V.: 25Vmin.: 0.03 max. W.V.: 16V/10V: 0.05 max. R9: 0.075max	linitial measurement for high dielectric constant type Perform a heat treatment at 150+0/-10 °C for 1h and then set			
		I.R. 25°C	More than 10,000MΩ or 500Ω • F (Whichever is smaller)		for 24+/-2h at room temperature. Perform the initial measurement.			
15	ESD	Appearance	No marking defects		Per AEC-Q200-002			
		Capacitance	Within the specified initial value.					
	Q or D.F. I.R. 25°C		Within the specified initial value.					
			More than 10,000M Ω or 500 Ω • F (Whichever is smaller)					
16			95% of the terminations is to be solde	ered evenly and continuously.	 (a) Preheat at 155°C for 4h. After preheating, immerse the capacitor in a solution of rosin ethanol 25(mass)%. Immerse in Sn-3.0Ag-0.5Cu solder solution at 245+/-5°C or an eutectic solder solution at 235+/-5°C for 5+0/-0.5s. (b) should be placed into steam aging for 8h+/-15min. After preheating, immerse the capacitor in a solution of rosin ethanol 25(mass)%. Immerse in Sn-3.0Ag-0.5Cu solder solution at 245+/-5°C or an eutectic solder solution at 235+/-5°C for 5+0/-0.5s. (c) should be placed into steam aging for 8h+/-15min. After preheating, immerse the capacitor in a solution of rosin ethanol 25(mass)%. Immerse in Sn-3.0Ag-0.5Cu solder solution or an eutectic solder solution for 120+/-5s at 260+/-5°C. 			
17	Electrical	Appearance	No defects or abnormalities		Visual inspection.			
	Chatacteri- zation	Capacitance	Shown in Rated value.		The capacitance/Q/D.F. should be measured at 25°C at the frequency and voltage shown in the table.			
		Q or D.F.	30pFmin. : Q≧1000 30pFmax.: Q≧400+20C C: Nominal Capacitance(pF)	R7/L8: W.V.: 25Vmin.: 0.025 max. W.V.: 16V/10V: 0.035 max. R9: 0.05max.	A C,5G			
		I.R. 25°C	More than 100,000MΩ or 1000Ω•F (Whichever is smaller)	More than 10,000M Ω or 500 Ω • F (Whichever is smaller)	The insulation resistance should be measured with a DC voltage not exceeding the rated voltage at 25°C and 125°C(for ΔC/R7)/ 150°C(for 5G/L8/R9) within 2 minutes of charging.			
		I.R. 125°C	More than $10,000M\Omega$ or $100\Omega \cdot F$ (Whichever is smaller)	More than 1,000MΩ or 10Ω·F (Whichever is smaller)				
		I.R. 150°C	More than $10,000M\Omega$ or $100\Omega \cdot F$ (Whichever is smaller)	More than 100MΩ or 1Ω•F (Whichever is smaller)				
		Dielectric No failure Strength		J	No failure should be observed when 250% of the rated voltage is applied between the terminations for 1 to 5s, provided the charge/discharge current is less than 50mA.			

			I c.	asification	1			
No	AEC-Q200	Test Item	Temperature	pecification.	AEC-Q200 Test Method			
			Compensating Type	High Dielectric Type				
18	Board Flex	Appearance	No marking defects		Solder the capacitor on the test substrate(glass epoxy board)			
				I	shown in Fig1.			
		Capacitance	Within +/-5.0% or +/-0.5pF	Within +/-10.0%	Then apply a force in the direction shown in Fig 2 for 60s.			
		Change	(Whichever is larger)		The soldering should be done by the reflow method and should be			
		Q or D.F.	Within the specified initial value		conducted with care so that the soldering is uniform and free of defects			
		Q OI D.I .	Within the specified fillial value	.	such as heat shock. Type a b c			
					Type a b c GCM03 0.3 0.9 0.3			
		I.R.	More than $10,000\text{M}\Omega$ or 500Ω	F	GCM15 0.5 J.5 0.6 GCM18 0.6 2.2 0.9			
		25°C	(Whichever is smaller)		GCM18 0.6 2.2 0.9 GCM21 0.8 3.0 1.3			
					GCM31 2.0 4.4 1.7			
				GCM32 2.0 4.4 2.6 (in mm)				
	Land $\frac{b}{b}$ $\phi 4.5$		+ ф4. 5	50 min.				
					Pressurizing speed:1.0mm/s			
				9	Pressurize			
			a	T 7 11				
			1	1				
			100)	Capacitance meter (High Dielectric Type)			
				t:1.6mm	45 45 Flexure: 3 (Temperature			
			Fig.	(GCM03/15:0.8mm)	Fig. 2 Compensating Type)			
19	Terminal	Appearance	No marking defects		Solder the capacitor on the test substrate(glass epoxy board)			
	Strength				shown in Fig3.			
		Capacitance	Within the specified initial value	э.	Then apply 18N* force in parallel with the test jig for 60s.			
		0 05	Marie de la contraction de		The soldering should be done either with an iron or using the reflow			
		Q or D.F.	Within the specified initial value	9.	method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock			
					*2N(GCM03/15)			
		I.R.	More than $10,000M\Omega$ or 500Ω	· F	Type a b c			
		 25℃	(Whichever is smaller)	•	GCM03 0.3 0.9 0.3			
			,		GCM15 0.4 1.5 0.5 GCM18 1.0 3.0 1.2			
					GCM21 1.2 4.0 1.65			
					GCM31 2.2 5.0 2.0 GCM32 2.2 5.0 2.9			
					C			
					(in mm)			
					t: 1.6mm			
			ラント゛	ф	GGW03/15. U. 8mm)			
					Solder resist			
					Baked electrode or			
					Fig.3			
20	Beam Load Test		Destruction value should be ex-	ceed following one.	Place the capacitor in the beam load fixture as Fig 4.			
			< Chip L dimension : 2.5mm ma		Apply a force.			
			· ·	ss > 0.5mm rank : 20N	< Chip Length : 2.5mm max. >			
			· ·	ss = 0.5mm rank : 8N	↓			
			1	ss = 0.3mm rank : 5N ss < 0.3mm rank : 2.5N	Iron Board			
			Ship thornes					
			< Chip L dimension : 3.2mm mi	n. >	XIIIIIIIIIIIIIII			
			Chip thicknes	ss < 1.25mm rank : 15N	< Chip Length : 3.2mm min. >			
			Chip thickness	ss ≧1.25mm rank : 54.5N	L↓			
					< > 0.6L			
					Fig.4			
					Fig.4			
					Speed supplied the Stress Load: *0.5mm/s			
					*GCM03: 0.1mm/s			
ь			1		GOMOO. O. IIIIIIIVO			

■ AEC-Q200 Murata Standard Specification and Test Methods

	Specifi	ication.	
No AEC-Q200 Test Item	Temperature Compensating Type	High Dielectric Type	AEC-Q200 Test Method
21 Capacitance Temperature	Nominal values of the temperature	R7: Within +/-15%	The capacitance change should be measured after 5 minutes
Characteristics	coefficient is shown in Rated value.	(-55°C to +125°C)	at each specified temp. stage.
		L8: Within +/-15%	Capacitance value as a reference is the value in step 3.
	Capacitance Change under 25°C	(-55°C to +125°C)	
i	is shown in Table A.	Within +15/-40%	(1)Temperature Compensating Type
		(+125°C to +150°C)	The capacitance drift is calculated by dividing the differences
	Capacitance Drift	R9: Within +/-15%	between the maximum and minimum measured values in the
	Within +/-0.2% or +/-0.05pF	(-55°C to +150°C)	step 1,3 and 5 by the cap. value in step 3.
	(Whichever is larger.)		Step Temperature(°C) 1

Table A

		Capac	itance Char	nge from 25	°C (%)	
Char.	-55°C		-30)℃	-10°C	
	Max.	Min.	Max.	Min.	Max.	Min.
5C/5G	0.58	-0.24	0.40	-0.17	0.25	-0.11

1.Tape Carrier Packaging(Packaging Code:D/E/W/F/L/J/K)

1.1 Minimum Quantity(pcs./reel)

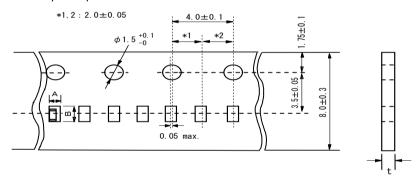
			φ180mm reel		φ330mm reel	
	Туре	Paper	^r Tape	Plastic Tape	Paper Tape	Plastic Tape
		Code:D/E	Code:W	Code:L	Code:J/ F	Code:K
GCM03	GCM03		30000(W8P1)		50000(W8P2)	
GCM15	5 (Dimensions Tolerance:±0.05)	10000(W8P2)	20000(W8P1)		50000(W8P2)	
GCIVITS	5 (Dimensions Tolerance:±0.1min.)	10000(W8P2)			40000(W8P2)	
GCM18		4000			10000	
	6	4000			10000	
GCM21	9	4000			10000	
	В			3000		10000
	9	4000			10000	
GCM31	M			3000		10000
	С			2000		6000
	9	4000			10000	
GCM32	M			3000		10000
GUNSZ	N			2000		8000
	R/D/E			1000		4000
	M			1000		5000
GCM43	N/R			1000		4000
	E			500		2000
COME	M			1000		5000
GCM55	N/R			1000		4000

1.2 Dimensions of Tape

(1)GCM03/15 < Paper Tape W8P2 CODE:D/E/J/F>

(in mm)

φ1.5

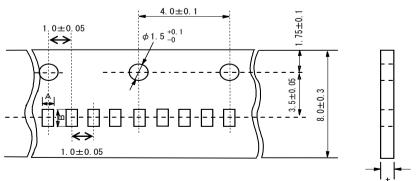


Type	Dimensions(Chip)		A*3	B *3	+			
Type		L	W	Т	A 3	БЗ	·	
GCM03	3	0.6±0.03	0.3±0.03	0.3±0.03	0.37	0.67	0.5 max.	
		1.0±0.05	0.5±0.05	0.5±0.05	0.65	1.15		
GCM15	5	1.0±0.1	0.5±0.1	0.5±0.1	0.7	1.2	0.8 max.	
		1.0±0.2	0.5±0.2	0.5±0.2	0.75	1.35		

*3 Nominal

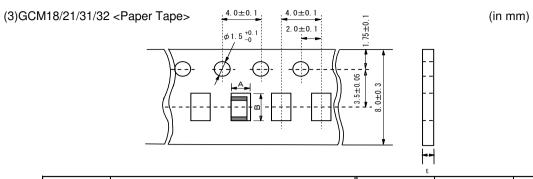
(2)GCM03/15 < Paper Tape W8P1 CODE:W>

(in mm)

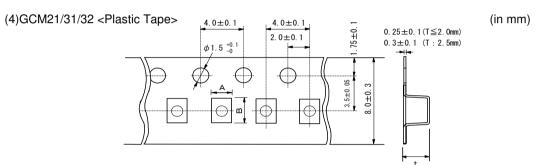


Type		Dimensions(Chip)		A*	В*	+	
Туре		L	W	Т	^	Ь	
GCM03	3	0.6±0.03	0.3±0.03	0.3±0.03	0.37	0.67	0.5 max.
GCM15	5	1.0±0.05	0.5±0.05	0.5±0.05	0.65	1.15	0.8 max.

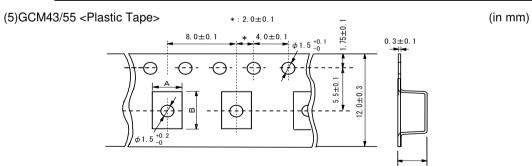
^{*} Nominal value



Туре		Dimensions(Chip)			A	В	+
Туре		١	W	Т		В	
GCM18	8	1.6±0.1	0.8±0.1	0.8±0.1	1.05±0.10	1.85±0.10	
GCM21	6	2.0±0.15	1.25±0.15	0.6±0.1	1.55±0.15	2.30±0.15	
GCIVIZI		2.0±0.13	1.2310.13	0.85±0.1	1.55±0.15	2.30±0.13	1.1 max.
GCM31	9	3.2±0.15	1.6±0.15	0.03±0.1	2.00±0.20	3.60±0.20	
GCM32		3.2±0.3	2.5±0.2	0.85 +0.15/-0.05	2.80±0.20	3.60±0.20	



Typo			Dimensions(Chip)		Α	В	+
Туре		L W		Т	^	В	,
GCM21	В	2.0±0.15	1.25±0.15	1.25±0.15	1.45±0.20	2.25±0.20	2.0 max.
GOIVIZI	D	2.0±0.2	1.25±0.2	1.25±0.2	1.50±0.20	2.30±0.20	2.0 IIIax.
	М	3.2±0.15	1.6±0.15	1.15±0.1			1.7 max.
GCM31	IVI	3.2±0.2	2 1.6±0.2 1.15±0.15 1.90±	1.90±0.20	3.50±0.20	1.7 IIIax.	
GOIVIST	С	3.210.2		1.6±0.2			2.5 max.
		3.2±0.3	1.6±0.3	1.6±0.3	2.10±0.20	3.60±0.20	Z.J IIIAX.
	М			1.15±0.1		3.50±0.20	1.7 max.
	N			1.35±0.15			2.5 max.
GCM32	R	3.2±0.3	2.5±0.2	1.8±0.2	2.80±0.20		3.0 max.
GOIVIOZ	D			2.0±0.2			J.U IIIAX.
	Е			2.5±0.2			3.7 max.
	_	3.2 +0.35/-0.3	2.5 +0.35/-0.2	2.5 +0.35/-0.2	3.10±0.20	3.80±0.20	4.0 max.



Туре		Dimensions(Chip)			A*1	B*1	+
Type		L	W	Т	ζ .	В 1	·
	М		3.2±0.3	1.15±0.1			2.5 max.
GCM43	Ν	4.5±0.4		1.35 +0.15/-0.05	3.6	4.9	
GOIVHS	R			1.8±0.2			
	Е			2.5±0.2			3.7 max.
	M		7±0.4 5.0±0.4	1.15±0.1	5.2	6.1	2.5 max.
GCM55	Ν	5.7±0.4		1.35±0.15			
	R			1.8±0.2			

^{*1} Nominal value

Fig.1 Package Chips



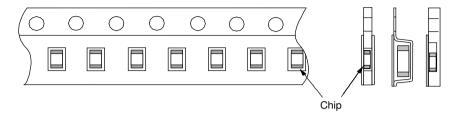
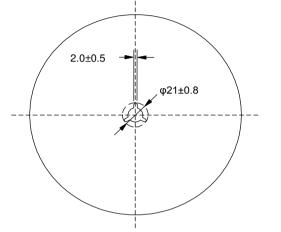


Fig.2 Dimensions of Reel



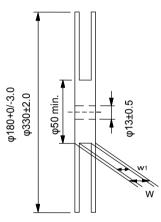
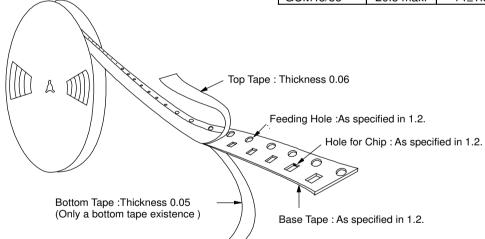


Fig.3 Taping Diagram

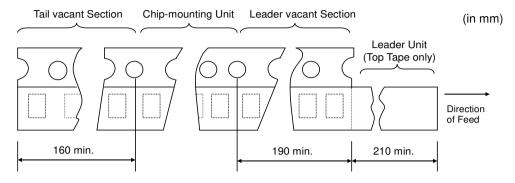
		W	W ₁
GCM32	max.	16.5 max.	10±1.5
GCM43/	55	20.5 max.	14±1.5



プ語め状態 単位:

- 1.3 Tapes for capacitors are wound clockwise shown in Fig.3.

 (The sprocket holes are to the right as the tape is pulled toward the user.)
- 1.4 Part of the leader and part of the vacant section are attached as follows.

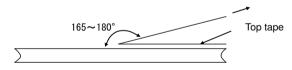


- 1.5 Accumulate pitch : 10 of sprocket holes pitch = 40 ± 0.3 mm
- 1.6 Chip in the tape is enclosed by top tape and bottom tape as shown in Fig.1.
- 1.7 The top tape and base tape are not attached at the end of the tape for a minimum of 5 pitches.
- 1.8 There are no jointing for top tape and bottom tape.
- 1.9 There are no fuzz in the cavity.
- 1.10 Break down force of top tape : 5N min.

 Break down force of bottom tape : 5N min. (Only a bottom tape existence)
- 図 デス 計算的状態 made by resin and appearance and dimension is shown in Fig 2.

 There are possibly to change the material and dimension due to some impairment.
 - 1.12 Peeling off force : 0.1N to 0.6N in the direction as shown below.

 * GCM03:0.05N to 0.5N



1.13 Label that show the customer parts number, our parts number, our company name, inspection number and quantity, will be put in outside of reel.

■Limitation of Applications

Please contact us before using our products for the applications listed below which require especially high reliability for the prevention of defects which might directly cause damage to the third party's life, body or property.

- ①Aircraft equipment ②Aerospace equipment ③Undersea equipment ④Power plant control equipment
- ⑤Medical equipment ⑥Transportation equipment(vehicles,trains,ships,etc.) ⑦Traffic signal equipment
- (1) Application of similar complexity and/or reliability requirements to the applications listed in the above.

■ Storage and Operation condition

- 1. The performance of chip multilayer ceramic capacitors (henceforth just "capacitors") may be affected by the storage conditions. Please use them promptly after delivery.
- 1-1. Maintain appropriate storage for the capacitors using the following conditions: Room Temperature of $+5^{\circ}$ C to $+40^{\circ}$ C and a Relative Humidity of 20% to 70%.

High temperature and humidity conditions and/or prolonged storage may cause deterioration of the packaging materials. If more than six months have elapsed since delivery, check packaging, mounting, etc. before use. In addition, this may cause oxidation of the electrodes. If more than one year has elapsed since delivery, also check the solderability before use.

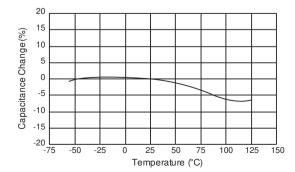
- 1-2. Corrosive gas can react with the termination (external) electrodes or lead wires of capacitors, and result in poor solderability. Do not store the capacitors in an atmosphere consisting of corrosive gas (e.g.,hydrogen sulfide, sulfur dioxide, chlorine, ammonia gas etc.).
- 1-3. Due to moisture condensation caused by rapid humidity changes, or the photochemical change caused by direct sunlight on the terminal electrodes and/or the resin/epoxy coatings, the solderability and electrical performance may deteriorate. Do not store capacitors under direct sunlight or in high huimidity conditions

■Rating

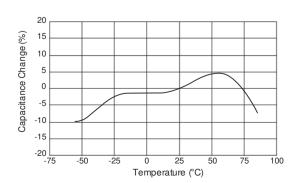
1.Temperature Dependent Characteristics

- 1. The electrical characteristics of the capacitor can change with temperature.
- 1-1. For capacitors having larger temperature dependency, the capacitance may change with temperature changes. The following actions are recommended in order to ensure suitable capacitance values.
 - (1) Select a suitable capacitance for the operating temperature range.
 - (2) The capacitance may change within the rated temperature. When you use a high dielectric constant type capacitor in a circuit that needs a tight (narrow) capacitance tolerance (e.g., a time-constant circuit), please carefully consider the temperature characteristics, and carefully confirm the various characteristics in actual use conditions and the actual system.

[Example of Temperature Caracteristics X7R(R7)] Sample: 0.1µF, Rated Voltage 50VDC



[Example of Temperature Characteristics X5R(R6)] Sample: 22µF, Rated Voltage 4VDC

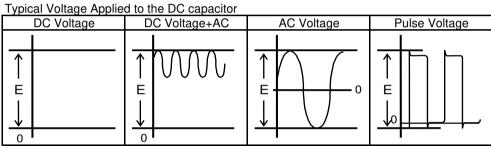


2.Measurement of Capacitance

- 1. Measure capacitance with the voltage and frequency specified in the product specifications.
- 1-1. The output voltage of the measuring equipment may decrease occasionally when capacitance is high. Please confirm whether a prescribed measured voltage is impressed to the capacitor.
- 1-2. The capacitance values of high dielectric constant type capacitors change depending on the AC voltage applied. Please consider the AC voltage characteristics when selecting a capacitor to be used in a AC circuit.

3. Applied Voltage

- 1. Do not apply a voltage to the capacitor that exceeds the rated voltage as called out in the specifications.
- 1-1. Applied voltage between the terminals of a capacitor shall be less than or equal to the rated voltage.
 - (1) When AC voltage is superimposed on DC voltage, the zero-to-peak voltage shall not exceed the rated DC voltage. When AC voltage or pulse voltage is applied, the peak-to-peak voltage shall not exceed the rated DC voltage.
 - (2) Abnormal voltages (surge voltage, static electricity, pulse voltage, etc.) shall not exceed the rated DC voltage.



(E : Maximum possible applied voltage.)

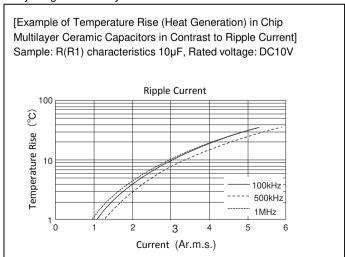
1-2. Influence of over voltage

Over voltage that is applied to the capacitor may result in an electrical short circuit caused by the breakdown of the internal dielectric layers.

The time duration until breakdown depends on the applied voltage and the ambient temperature.

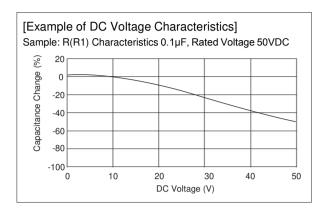
4. Type of Applied Voltage and Self-heating Temperature

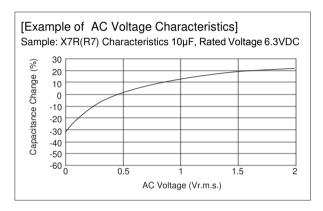
- 1. Confirm the operating conditions to make sure that no large current is flowing into the capacitor due to the continuous application of an AC voltage or pulse voltage.
 - When a DC rated voltage product is used in an AC voltage circuit or a pulse voltage circuit, the AC current or pulse current will flow into the capacitor; therefore check the self-heating condition.
 - Please confirm the surface temperature of the capacitor so that the temperature remains within the upper limits of the operating temperature, including the rise in temperature due to self-heating. When the capacitor is used with a high-frequency voltage or pulse voltage, heat may be generated by dielectric loss.
- <Applicable to Rated Voltage of less than 100VDC>
 The load should be contained so that the self-heating of the capacitor body remains below 20°C , when measuring at an ambient temperature of 25°C.



5. DC Voltage and AC Voltage Characteristic

- The capacitance value of a high dielectric constant type capacitor changes depending on the DC voltage applied. Please consider the DC voltage characteristics when a capacitor is selected for use in a DC circuit.
- 1-1. The capacitance of ceramic capacitors may change sharply depending on the applied voltage. (See figure) Please confirm the following in order to secure the capacitance.
- (1) Determine whether the capacitance change caused by the applied voltage is within the allowed range.
- (2) In the DC voltage characteristics, the rate of capacitance change becomes larger as voltage increases, even if the applied voltage is below the rated voltage. When a high dielectric constant type capacitor is used in a circuit that requires a tight (narrow) capacitance tolerance (e.g., a time constant circuit), please carefully consider the voltage characteristics, and confirm the various characteristics in the actual operating conditions of the system.
- The capacitance values of high dielectric constant type capacitors changes depending on the AC voltage applied.
 Please consider the AC voltage characteristics when selecting a capacitor to be used in a AC circuit.

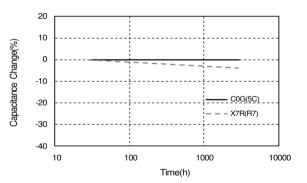




6. Capacitance Aging

 The high dielectric constant type capacitors have an Aging characteristic in which the capacitance value decreases with the passage of time.
 When you use a high dielectric constant type capacitors in a circuit that needs a tight (narrow) capacitance tolerance (e.g., a time-constant circuit), please carefully consider the characteristics of these capacitors, such as their aging, voltage, and temperature characteristics. In addition, check capacitors using your actual appliances at the intended environment and operating conditions.

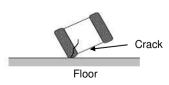
[Example of Change Over Time (Aging characteristics)]

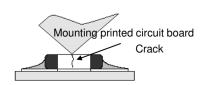


7.Vibration and Shock

- 1. Please confirm the kind of vibration and/or shock, its condition, and any generation of resonance.

 Please mount the capacitor so as not to generate resonance, and do not allow any impact on the terminals.
- Mechanical shock due to being dropped may cause damage or a crack in the dielectric material of the capacitor.Do not use a dropped capacitor because the quality and reliability may be deteriorated.
- 3. When printed circuit boards are piled up or handled, the corner of another printed circuit board should not be allowed to hit the capacitor in order to avoid a crack or other damage to the capacitor.

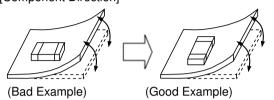




■ Soldering and Mounting

1.Mounting Position

- 1. Confirm the best mounting position and direction that minimizes the stress imposed on the capacitor during flexing or bending the printed circuit board.
- 1-1.Choose a mounting position that minimizes the stress imposed on the chip during flexing or bending of the board. [Component Direction]



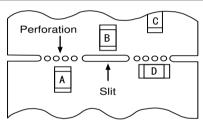
Locate chip horizontal to the direction in which stress acts.

[Chip Mounting Close to Board Separation Point]

It is effective to implement the following measures, to reduce stress in separating the board.

It is best to implement all of the following three measures; however, implement as many measures as possible to reduce stress.

Contents of Measures	Stress Level
(1) Turn the mounting direction of the component parallel to the board separation surface.	A > D*1
(2) Add slits in the board separation part.	A > B
(3) Keep the mounting position of the component away from the board separation surface.	A > C

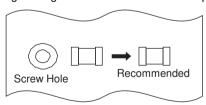


*1 A > D is valid when stress is added vertically to the perforation as with Hand Separation. If a Cutting Disc is used, stress will be diagonal to the PCB, therefore A > D is invalid.



[Mounting Capacitors Near Screw Holes]

When a capacitor is mounted near a screw hole, it may be affected by the board deflection that occurs during the tightening of the screw. Mount the capacitor in a position as far away from the screw holes as possible.



2.Information before Mounting

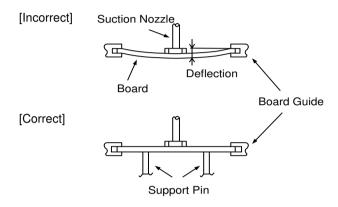
- 1. Do not re-use capacitors that were removed from the equipment.
- 2. Confirm capacitance characteristics under actual applied voltage.
- 3. Confirm the mechanical stress under actual process and equipment use.
- 4. Confirm the rated capacitance, rated voltage and other electrical characteristics before assembly.
- 5. Prior to use, confirm the solderability of capacitors that were in long-term storage.
- 6. Prior to measuring capacitance, carry out a heat treatment for capacitors that were in long-term storage.
- 7. The use of Sn-Zn based solder will deteriorate the reliability of the MLCC.

 Please contact our sales representative or product engineers on the use of Sn-Zn based solder in advance.



3. Maintenance of the Mounting (pick and place) Machine

- 1. Make sure that the following excessive forces are not applied to the capacitors. Check the mounting in the actual device under actual use conditions ahead of time.
- 1-1. In mounting the capacitors on the printed circuit board, any bending force against them shall be kept to a minimum to prevent them from any damage or cracking. Please take into account the following precautions and recommendations for use in your process.
 - (1) Adjust the lowest position of the pickup nozzle so as not to bend the printed circuit board.



2.Dirt particles and dust accumulated in the suction nozzle and suction mechanism prevent the nozzle from moving smoothly. This creates excessive force on the capacitor during mounting, causing cracked chips. Also, the locating claw, when worn out, imposes uneven forces on the chip when positioning, causing cracked chips. The suction nozzle and the locating claw must be maintained, checked and replaced periodically.

4-1.Reflow Soldering

- When sudden heat is applied to the components, the mechanical strength of the components will decrease because a sudden temperature change causes deformation inside the components. In order to prevent mechanical damage to the components, preheating is required for both the components and the PCB.
 Preheating conditions are shown in table 1. It is required to keep the temperature differential between the solder and the components surface (ΔT) as small as possible.
- 2. When components are immersed in solvent after mounting, be sure to maintain the temperature difference (ΔT) between the component and the solvent within the range shown in the table 1.

Table 1

rable i		
Series	Chip Dimension(L/W) Code	Temperature Differential
GC□	03/15/18/21/31	ΔT≦190°C
GC□	32	ΔΤ≦130°C

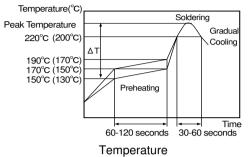
Recommended Conditions

- toooninionada oonadaana				
	Pb-Sn Solder	Lead Free Solder		
Peak Temperature	230 to 250°C	240 to 260°C		
Atmosphere	Air	Air or N ₂		

Pb-Sn Solder: Sn-37Pb

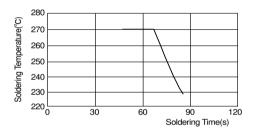
Lead Free Solder: Sn-3.0Ag-0.5Cu

[Standard Conditions for Reflow Soldering]



Incase of Lead Free Solder
(): In case of Pb-Sn Solder

[Allowable Reflow Soldering Temperature and Time]



In the case of repeated soldering, the accumulated soldering time must be within the range shown above.

- 3. When a capacitor is mounted at a temperature lower than the peak reflow temperature recommended by the solder manufacturer, the following quality problems can occur. Consider factors such as the placement of peripheral components and the reflow temperature setting to prevent the capacitor's reflow temperature from dropping below the peak temperature specified. Be sure to evaluate the mounting situation beforehand and verify that none of the following problems occur.
- ·Drop in solder wettability
- ·Solder voids
- ·Possible occurrence of whiskering
- ·Drop in bonding strength
- ·Drop in self-alignment properties
- ·Possible occurrence of tombstones and/or shifting on the land patterns of the circuit board
- 4. Optimum Solder Amount for Reflow Soldering
- 4-1. Overly thick application of solder paste results in a excessive solder fillet height.

 This makes the chip more susceptible to mechanical and thermal stress on the board and may cause the chips to crack.
- 4-2. Too little solder paste results in a lack of adhesive strength on the termination, which may result in chips breaking loose from the PCB.
- 4-3. Please confirm that solder has been applied smoothly to the termination.

Inverting the PCB

Make sure not to impose any abnormal mechanical shocks to the PCB.

Gradua

Cooling

Soldering

5 seconds max.

4-2.Flow Soldering

1. Do not apply flow soldering to chips not listed in Table 2.

Table 2

14516 E						
Series	Chip Dimension (L/W) Code	Temperature Differential				
GC□	18/21/31	ΔT≦150°C				

(Except for Temperature Characteristics:0C(CHA),5G(X8G),R9(X8R),L8(X8L),M8(X8M))

- 2. When sudden heat is applied to the components, the mechanical strength of the components will decrease because a sudden temperature change causes deformation inside the components. In order to prevent mechanical damage to the components, preheating is required for both of the components and the PCB. Preheating conditions are shown in table 2. It is required to keep the temperature differential between the solder and the components surface (ΔT) as low as possible.
- 3. Excessively long soldering time or high soldering temperature can result in leaching of the terminations, causing poor adhesion or a reduction in capacitance value due to loss of contact between the inner electrodes and terminations.
- 4. When components are immersed in solvent after mounting, be sure to maintain the temperature differential (ΔT) between the component and solvent within the range shown in the table 2.

Preheating

30-90 seconds

ΛТ

[Standard Conditions for Flow Soldering]

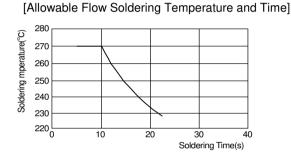
Temperature(°C

Temperature

Preheating Peak Temperature

Soldering

Peak



In the case of repeated soldering, the accumulated soldering time must be within the range shown above.

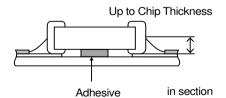
Recommended Conditions

	Pb-Sn Solder	Lead Free Solder
Preheating Peak Temperature	90 to 110°C	100 to 120°C
Soldering Peak Temperature	240 to 250°C	250 to 260°C
Atmosphere	Air	Air or N2

Pb-Sn Solder: Sn-37Pb

Lead Free Solder: Sn-3.0Ag-0.5Cu

- 5. Optimum Solder Amount for Flow Soldering
- 5-1. The top of the solder fillet should be lower than the thickness of the components. If the solder amount is excessive, the risk of cracking is higher during board bending or any other stressful condition.



4-3. Correction of Soldered Portion

When sudden heat is applied to the capacitor, distortion caused by the large temperature difference occurs internally, and can be the cause of cracks. Capacitors also tend to be affected by mechanical and thermal stress depending on the board preheating temperature or the soldering fillet shape, and can be the cause of cracks. Please refer to "1. PCB Design" or "3. Optimum solder amount" for the solder amount and the fillet shapes.

- 1. Correction with a Soldering Iron
 - 1-1. In order to reduce damage to the capacitor, be sure to preheat the capacitor and the mounting board.

 Preheat to the temperature range shown in Table 3. A hot plate, hot air type preheater, etc. can be used for preheating.
- 1-2. After soldering, do not allow the component/PCB to cool down rapidly.
- 1-3. Perform the corrections with a soldering iron as quickly as possible. If the soldering iron is applied too long, there is a possibility of causing solder leaching on the terminal electrodes, which will cause deterioration of the adhesive strength and other problems.

Table 3

Series	Chip Dimension (L/W) Code	Temperature of Soldering Iron tip	Preheating Temperature	Temperature Differential(ΔT)	Atmosphere
GC□	03/15/18/21/31	350°C max.	150°C min.	ΔT≦190°C	Air
GC□	32	280°C max.	150°C min.	ΔT≦130°C	Air

^{*}Applicable for both Pb-Sn and Lead Free Sold Pb-Sn Solder: Sn-37Pb

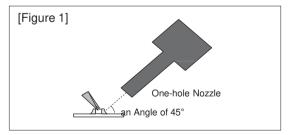
Lead Free Solder: Sn-3.0Ag-0.5Cu

- 2. Correction with Spot Heater
 - Compared to local heating with a soldering iron, hot air heating by a spot heater heats the overall component and board, therefore, it tends to lessen the thermal shock. In the case of a high density mounted board, a spot heater can also prevent concerns of the soldering iron making direct contact with the component.
- 2-1. If the distance from the hot air outlet of the spot heater to the component is too close, cracks may occur due to thermal shock. To prevent this problem, follow the conditions shown in Table 4.
- 2-2. In order to create an appropriate solder fillet shape, it is recommended that hot air be applied at the angle shown in Figure 1.

Table 4

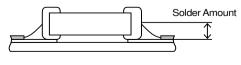
Table +	
Distance	5mm or more
Hot Air Application angle	45° *Figure 1
Hot Air Temperature Nozzle Outlet	400°C max.
	Less than 10 seconds
Application Time	(3216M / 1206 size or smaller)
	Less than 30 seconds
	(3225M / 1210 size or larger)

(3216M, 3225M: Metric size code)



- 3. Optimum solder amount when re-working with a soldering iron
- 3-1. If the solder amount is excessive, the risk of cracking is higher during board bending or any other stressful condition. Too little solder amount results in a lack of adhesive strength on the outer electrode termination, which may result in chips breaking loose from the PCB. Please confirm that solder has been applied smoothly is
- 3-2. A soldering iron with a tip of ø3mm or smaller should be used. It is also necessary to keep the soldering iron from touching the components during the re-work.
- 3-3. Solder wire with Ø0.5mm or smaller is required for soldering.

and rising to the end surface of the chip.



in section

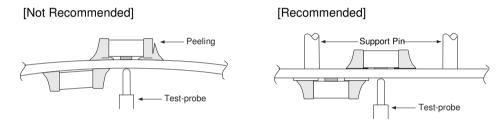
^{*} Please manage Δ T in the temperature of soldering iron and the preheating temperature.

5.Washing

Excessive ultrasonic oscillation during cleaning can cause the PCBs to resonate, resulting in cracked chips or broken solder joints. Before starting your production process, test your cleaning equipment / process to insure it does not degrade the capacitors.

6.Electrical Test on Printed Circuit Board

- 1. Confirm position of the support pin or specific jig, when inspecting the electrical performance of a capacitor after mounting on the printed circuit board.
 - 1-1. Avoid bending the printed circuit board by the pressure of a test-probe, etc. The thrusting force of the test probe can flex the PCB, resulting in cracked chips or open solder joints. Provide support pins on the back side of the PCB to prevent warping or flexing. Install support pins as close to the test-probe as possible.
 - 1-2. Avoid vibration of the board by shock when a test -probe contacts a printed circuit board.



7. Printed Circuit Board Cropping

- 1. After mounting a capacitor on a printed circuit board, do not apply any stress to the capacitor that caused bending or twisting the board.
 - 1-1. In cropping the board, the stress as shown may cause the capacitor to crack. Cracked capacitors may cause deterioration of the insulation resistance, and result in a short. Avoid this type of stress to a capacitor.



- 2. Check the cropping method for the printed circuit board in advance.
 - 2-1. Printed circuit board cropping shall be carried out by using a jig or an apparatus (Disc separator, router type separator, etc.) to prevent the mechanical stress that can occur to the board.

Board Separation Method	Hand Separation	(1) Board Separation Jig	Board Separation Apparatus		
Board Separation Method	Nipper Separation	(1) Board Separation sig	Disc Separator	3) Router Type Separator	
Level of stress on board	High	Medium	Medium	Low	
Recommended	×	Δ*	Δ*	0	
Hand and nipper separation apply a Notes level of stress. Use another metho		Board handling Board bending direction Layout of capacitors	Board handling Layout of slits Design of V groove Arrangement of blades Controlling blade life	Board handling	

^{*} When a board separation jig or disc separator is used, if the following precautions are not observed, a large board deflection stress will occur and the capacitors may crack.
Use router type separator if at all possible.

(1) Example of a suitable jig

[Outline of jig]

[In the case of Single-side Mounting]

An outline of the board separation jig is shown as follows.

Recommended example: Stress on the component mounting position can be minimized by holding the portion close to the jig, and bend in the direction towards the side where the capacitors are mounted. Not recommended example: The risk of cracks occurring in the capacitors increases due to large stress being applied to the component mounting position, if the portion away from the jig is held and bent in the direction opposite the side where the capacitors are mounted.

Printed Circuit Board V-groove

Board Cropping Jig



[In the case of Double-sided Mounting]

Since components are mounted on both sides of the board, the risk of cracks occurring can not be avoided with the above method. Therefore, implement the following measures to prevent stress from being applied to the components. (Measures)

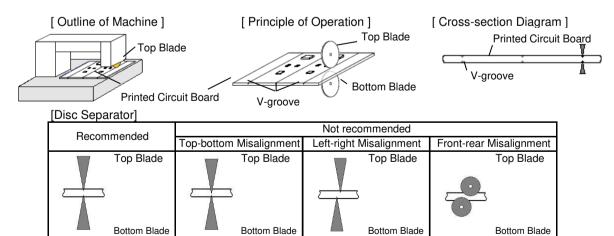
- (1) Consider introducing a router type separator.
 - If it is difficult to introduce a router type separator, implement the following measures. (Refer to item 1. Mounting Position)
- (2) Mount the components parallel to the board separation surface.
- (3) When mounting components near the board separation point, add slits in the separation position near the component.
- (4) Keep the mounting position of the components away from the board separation point.

(2) Example of a Disc Separator

An outline of a disc separator is shown as follows. As shown in the Principle of Operation, the top blade and bottom blade are aligned with the V-grooves on the printed circuit board to separate the board. In the following case, board deflection stress will be applied and cause cracks in the capacitors.

- (1) When the adjustment of the top and bottom blades are misaligned, such as deviating in the top-bottom, left-right or front-rear directions
- (2) The angle of the V groove is too low, depth of the V groove is too shallow, or the V groove is misaligned top-bottom

IF V groove is too deep, it is possible to brake when you handle and carry it. Carefully design depth of the V groove with consideration about strength of material of the printed circuit board.



[V-groove Design]

Example of Recommended V-groove Design

Left-right Misalignment

Low-Angle

Depth too Shallow

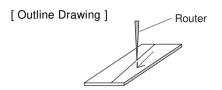
Depth too Deep

△Caution

(3) Example of Router Type Separator

The router type separator performs cutting by a router rotating at a high speed. Since the board does not bend in the cutting process, stress on the board can be suppressed during board separation.

When attaching or removing boards to/from the router type separator, carefully handle the boards to prevent bending.



8. Assembly

1. Handling

If a board mounted with capacitors is held with one hand, the board may bend.

Firmly hold the edges of the board with both hands when handling.

If a board mounted with capacitors is dropped, cracks may occur in the capacitors.

Do not use dropped boards, as there is a possibility that the quality of the capacitors may be impaired.

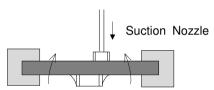
2. Attachment of Other Components

2-1. Mounting of Other Components

Pay attention to the following items, when mounting other components on the back side of the board after capacitors have been mounted on the opposite side.

When the bottom dead point of the suction nozzle is set too low, board deflection stress may be applied to the capacitors on the back side (bottom side), and cracks may occur in the capacitors.

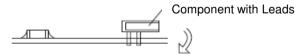
- After the board is straightened, set the bottom dead point of the nozzle on the upper surface of the board.
- · Periodically check and adjust the bottom dead point.



2-2. Inserting Components with Leads into Boards

When inserting components (transformers, IC, etc.) into boards, bending the board may cause cracks in the capacitors or cracks in the solder. Pay attention to the following.

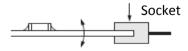
- Increase the size of the holes to insert the leads, to reduce the stress on the board during insertion.
- · Fix the board with support pins or a dedicated jig before insertion.
- · Support below the board so that the board does not bend. When using support pins on the board, periodically confirm that there is no difference in the height of each support pin.



2-3. Attaching/Removing Sockets and/or Connectors

Insertion and removal of sockets and connectors, etc., might cause the board to bend.

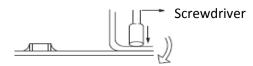
Please insure that the board does not warp during insertion and removal of sockets and connectors, etc., or the bending may damage mounted components on the board.



2-4. Tightening Screws

The board may be bent, when tightening screws, etc. during the attachment of the board to a shield or chassis. Pay attention to the following items before performing the work.

- · Plan the work to prevent the board from bending.
- · Use a torque screwdriver, to prevent over-tightening of the screws.
- The board may bend after mounting by reflow soldering, etc. Please note, as stress may be applied to the chips by forcibly flattening the board when tightening the screws.



Others

1. Under Operation of Equipment

- 1-1. Do not touch a capacitor directly with bare hands during operation in order to avoid the danger of an electric shock.
- 1-2. Do not allow the terminals of a capacitor to come in contact with any conductive objects (short-circuit). Do not expose a capacitor to a conductive liquid, inducing any acid or alkali solutions.
- 1-3. Confirm the environment in which the equipment will operate is under the specified conditions.
 - Do not use the equipment under the following environments.
 - (1) Being spattered with water or oil.
 - (2) Being exposed to direct sunlight.
 - (3) Being exposed to ozone, ultraviolet rays, or radiation.
 - (4) Being exposed to toxic gas (e.g., hydrogen sulfide, sulfur dioxide, chlorine, ammonia gas etc.)
 - (5) Any vibrations or mechanical shocks exceeding the specified limits.
 - (6) Moisture condensing environments.
- 1-4. Use damp proof countermeasures if using under any conditions that can cause condensation.

2. Others

2-1. In an Emergency

- (1) If the equipment should generate smoke, fire, or smell, immediately turn off or unplug the equipment.

 If the equipment is not turned off or unplugged, the hazards may be worsened by supplying continuous power.
- (2) In this type of situation, do not allow face and hands to come in contact with the capacitor or burns may be caused by the capacitor's high temperature.

2-2. Disposal of waste

When capacitors are disposed of, they must be burned or buried by an industrial waste vendor with the appropriate licenses.

2-3. Circuit Design

(1) Addition of Fail Safe Function

Capacitors that are cracked by dropping or bending of the board may cause deterioration of the insulation resistance, and result in a short. If the circuit being used may cause an electrical shock, smoke or fire when a capacitor is shorted, be sure to install fail-safe functions, such as a fuse, to prevent secondary accidents.

(2) This series are not safety standard certified products.

2-4. Remarks

Failure to follow the cautions may result, worst case, in a short circuit and smoking when the product is used. The above notices are for standard applications and conditions. Contact us when the products are used in special mounting conditions.

Select optimum conditions for operation as they determine the reliability of the product after assembly. The data herein are given in typical values, not guaranteed ratings.

Rating

1.Operating Temperature

- 1. The operating temperature limit depends on the capacitor.
- 1-1. Do not apply temperatures exceeding the maximum operating temperature.

 It is necessary to select a capacitor with a suitable rated temperature that will cover the operating temperature range.

 It is also necessary to consider the temperature distribution in equipment and the seasonal temperature variable factor.
- 1-2. Consider the self-heating factor of the capacitor

 The surface temperature of the capacitor shall not exceed the maximum operating temperature including self-heating.

2.Atmosphere Surroundings (gaseous and liquid)

- 1. Restriction on the operating environment of capacitors.
- 1-1. Capacitors, when used in the above, unsuitable, operating environments may deteriorate due to the corrosion of the terminations and the penetration of moisture into the capacitor.
- 1-2. The same phenomenon as the above may occur when the electrodes or terminals of the capacitor are subject to moisture condensation.
- 1-3. The deterioration of characteristics and insulation resistance due to the oxidization or corrosion of terminal electrodes may result in breakdown when the capacitor is exposed to corrosive or volatile gases or solvents for long periods of time.

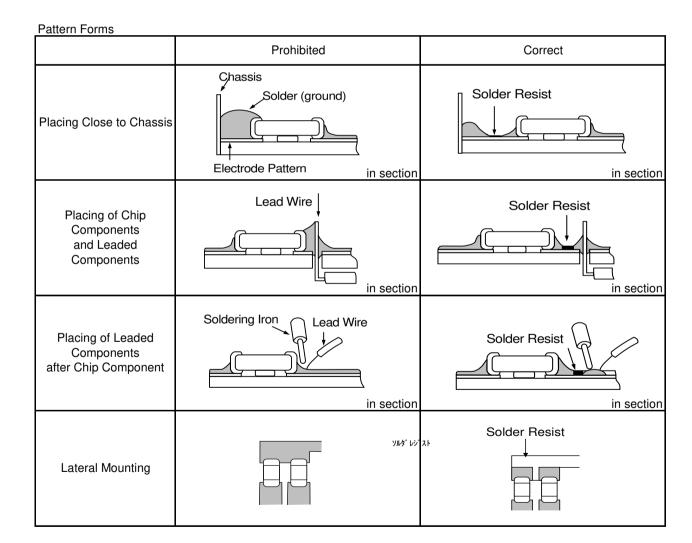
3.Piezo-electric Phenomenon

 When using high dielectric constant type capacitors in AC or pulse circuits, the capacitor itself vibrates at specific frequencies and noise may be generated.
 Moreover, when the mechanical vibration or shock is added to capacitor, noise may occur.

■Soldering and Mounting

1.PCB Design

- 1. Notice for Pattern Forms
- 1-1. Unlike leaded components, chip components are susceptible to flexing stresses since they are mounted directly on the substrate.
 - They are also more sensitive to mechanical and thermal stresses than leaded components.
 - Excess solder fillet height can multiply these stresses and cause chip cracking.
 - When designing substrates, take land patterns and dimensions into consideration to eliminate the possibility of excess solder fillet height.
- 1-2. There is a possibility of chip cracking caused by PCB expansion/contraction with heat, because stress on a chip is different depending on PCB material and structure. When the thermal expansion coefficient greatly differs between the board used for mounting and the chip, it will cause cracking of the chip due to the thermal expansion and contraction. When capacitors are mounted on a fluorine resin printed circuit board or on a single-layered glass epoxy board, it may also cause cracking of the chip for the same reason.



2. Land Dimensions

Please confirm the suitable land dimension by evaluating of the actual SET / PCB.

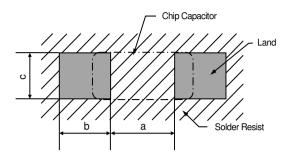


Table 1 Flow Soldering Method

Table 11 low coldening Method							
Series	Chip Dimension (L/W) Code	Chip(L×W)	а	b	С		
GC□	18	1.6×0.8	0.6 to 1.0	0.8 to 0.9	0.6 to 0.8		
GC□	21	2.0×1.25	1.0 to 1.2	0.9 to 1.0	0.8 to 1.1		
GC□	31	3.2×1.6	2.2 to 2.6	1.0 to 1.1	1.0 to 1.4		

Flow soldering can only be used for products with a chip size of 1.6x0.8mm to 3.2x1.6mm. (in mm)
Resistance to PCB bending stress may be improved by designing the "a" dimension with solder resist.

Table 2 Reflow Soldering Method

Series	Chip Dimension (L/W) Code	Chip(L×W) (Dimensions Tolerance)	а	b	С
GC□	03	0.6×0.3 (±0.03)	0.2 to 0.25	0.2 to 0.3	0.25 to 0.35
GC□	15	1.0×0.5 (within ±0.10)	0.3 to 0.5	0.35 to 0.45	0.4 to 0.6
		1.0×0.5 (±0.20)	0.4 to 0.6	0.4 to 0.5	0.5 to 0.7
GC□	18	1.6×0.8 (±0.10)	0.6 to 0.8	0.6 to 0.7	0.6 to 0.8
		1.6×0.8 (±0.20)	0.7 to 0.9	0.7 to 0.8	0.8 to 1.0
GC□	21	2.0×1.25 (±0.15)	1.2	0.6 to 0.8	1.2 to 1.4
		2.0×1.25 (±0.20)	1.0 to 1.4	0.6 to 0.8	1.2 to 1.4
GC□	31	3.2×1.6 (within±0.20)	1.8 to 2.0	0.9 to 1.2	1.5 to 1.7
		3.2×1.6 (±0.30)	1.9 to 2.1	1.0 to 1.3	1.7 to 1.9
GC□	32	3.2×2.5	2.0 to 2.4	1.0 to 1.2	1.8 to 2.3

(in mm)